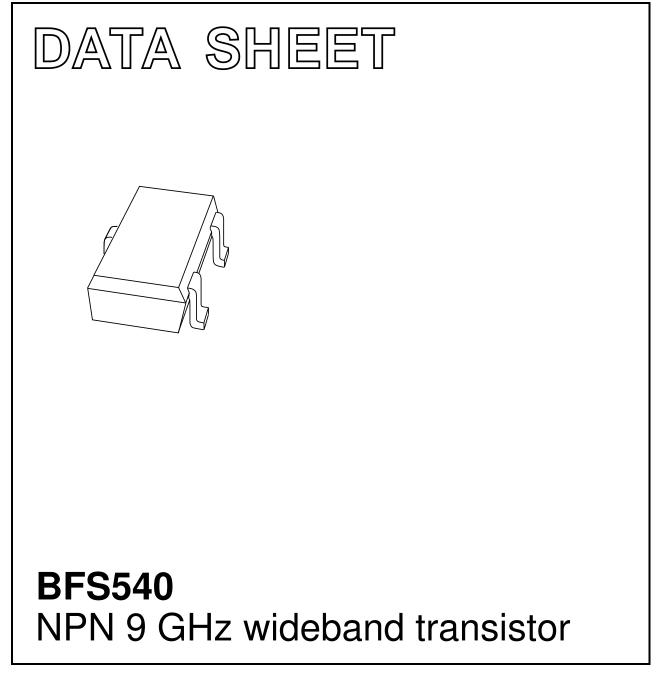
# DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1997 Dec 05 2000 May 30



DESCRIPTION

package.

PINNING

PIN

1

2

3

NPN transistor in a SOT323 plastic

base

emitter

collector

DESCRIPTION

#### **FEATURES**

- High power gain
- Low noise figure
- · High transition frequency
- · Gold metallization ensures excellent reliability
- SOT323 package.

#### **APPLICATIONS**

RF wideband amplifier applications such as satellite TV systems and RF portable communication equipment with signal frequencies up to 2 GHz.

#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	-	-	20	V
V <sub>CEO</sub>	collector-emitter voltage	open base	_	-	15	V
I <sub>C</sub>	DC collector current		-	-	120	mA
P <sub>tot</sub>	total power dissipation	$T_s \le 80 \text{ °C}; \text{ note } 1$	-	-	500	mW
h <sub>FE</sub>	DC current gain	$I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; T_{j} = 25 \text{ °C}$	100	120	250	
f <sub>T</sub>	transition frequency	$I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; f = 1 \text{ GHz};$ $T_{amb} = 25 \text{ °C}$	-	9	-	GHz
G <sub>UM</sub>	maximum unilateral power gain	$I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; f = 900 \text{ MHz};$ $T_{amb} = 25 \text{ °C}$	-	14	-	dB
F	noise figure	$I_{C} = 10 \text{ mA}; V_{CE} = 8 \text{ V}; f = 900 \text{ MHz};$ $T_{amb} = 25 \text{ °C}$	-	1.3	1.7	dB

#### Note

1.  $T_s$  is the temperature at the soldering point of the collector tab.

#### LIMITING VALUES

In accordance with the Absolute Maximum System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	_	20	V
V <sub>CES</sub>	collector-emitter voltage	R <sub>BE</sub> = 0	_	15	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	2.5	V
I <sub>C</sub>	DC collector current		-	120	mA
P <sub>tot</sub>	total power dissipation	$T_s \le 80 \ ^{\circ}C$ ; note 1	-	500	mW
T <sub>stg</sub>	storage temperature		-65	150	°C
Tj	junction temperature		-	175	°C

#### Note

1. T<sub>s</sub> is the temperature at the soldering point of the collector tab.

# **Product specification**

**BFS540** 

] 3 Top view MBC870 Marking code: N4. Fig.1 SOT323.

#### 2

### **BFS540**

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-s</sub>	thermal resistance from junction to soldering point	$T_s \le 80 \ ^\circ C$ ; note 1	190	K/W

#### Note

1.  $T_s$  is the temperature at the soldering point of the collector tab.

#### **CHARACTERISTICS**

 $T_i = 25 \ ^{\circ}C$  unless otherwise specified.

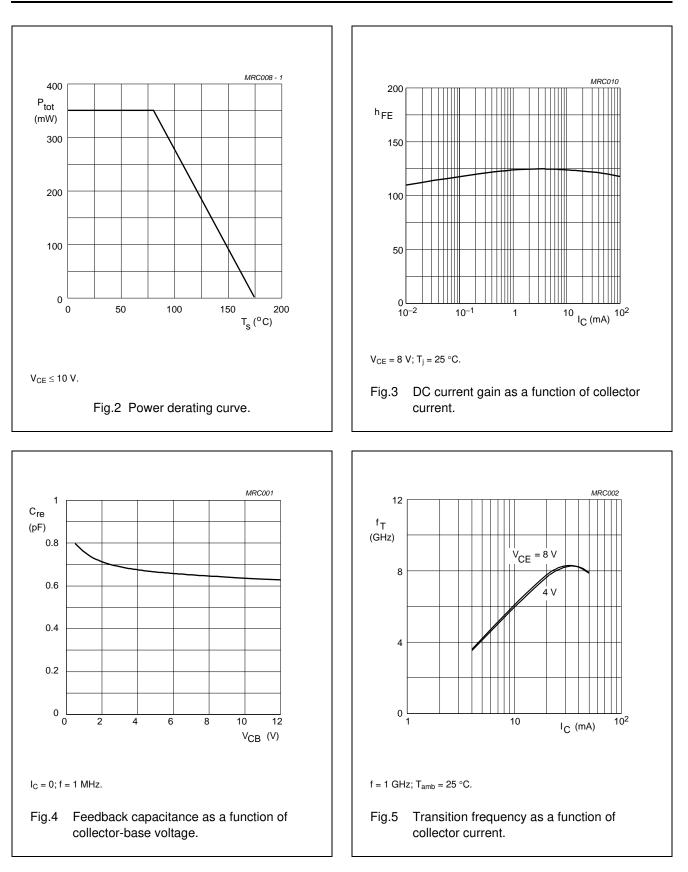
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector cut-off current	I <sub>E</sub> = 0; V <sub>CE</sub> = 8 V	-	-	50	nA
h <sub>FE</sub>	DC current gain	I <sub>C</sub> = 40 mA; V <sub>CE</sub> = 8 V	100	120	250	
Ce	emitter capacitance	$I_{C} = i_{c} = 0; V_{EB} = 0.5 V; f = 1 MHz$	_	2	-	pF
C <sub>c</sub>	collector capacitance	$I_E = i_e = 0; V_{CB} = 8 V; f = 1 MHz$	-	0.9	-	pF
C <sub>re</sub>	feedback capacitance	$I_{C} = 0; V_{CB} = 8 V; f = 1 MHz$	-	0.6	-	pF
f <sub>T</sub>	transition frequency	$I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; f = 1 \text{ GHz};$ $T_{amb} = 25 \text{ °C}$	-	9	-	GHz
G <sub>UM</sub>	maximum unilateral power gain (note 1)	$I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; f = 900 \text{ MHz}; T_{amb} = 25 \text{ °C}$	-	14	-	dB
		$I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; f = 2 \text{ GHz};$ $T_{amb} = 25 \text{ °C}$	-	8	-	dB
$ s_{21} ^2$	insertion power gain	$I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; f = 900 \text{ MHz}; T_{amb} = 25 \text{ °C}$	12	13	-	dB
F	noise figure	$\Gamma_{s} = \Gamma_{opt}$ ; I <sub>C</sub> = 10 mA; V <sub>CE</sub> = 8 V; f = 900 MHz; T <sub>amb</sub> = 25 °C	-	1.3	1.8	dB
		$\label{eq:Gamma} \begin{array}{l} \Gamma_{s}=\Gamma_{opt}; \ I_{C}=40 \ \text{mA}; \ V_{CE}=8 \ \text{V}; \\ f=900 \ \text{MHz}; \ T_{amb}=25 \ ^{\circ}\text{C} \end{array}$	-	1.9	2.4	dB
		$\label{eq:GHZ} \begin{split} \Gamma_{s} &= \Gamma_{opt}; \ I_{C} = 10 \ \text{mA}; \ V_{CE} = 8 \ \text{V}; \\ f &= 2 \ \text{GHz}; \ T_{amb} = 25 \ ^{\circ}\text{C} \end{split}$	-	2.1	-	dB
P <sub>L1</sub>	output power at 1 dB gain compression	$I_c$ = 40 mA; V <sub>CE</sub> = 8 V; R <sub>L</sub> = 50 Ω; f = 900 MHz; T <sub>amb</sub> = 25 °C	-	21	_	dBm
ITO	third order intercept point	note 2	_	34	_	dBm

#### Notes

1.  $G_{UM}$  is the maximum unilateral power gain, assuming  $s_{12}$  is zero and

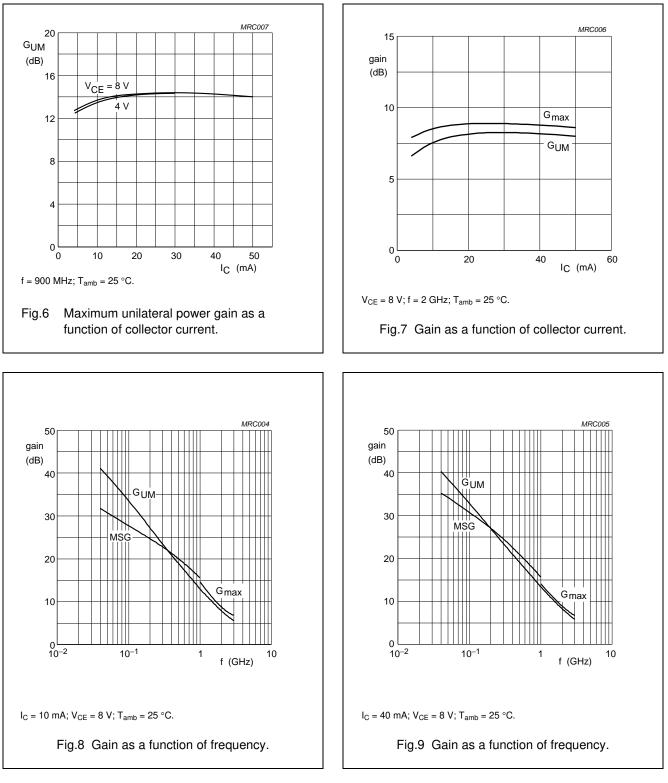
$$G_{UM} = 10 \log \frac{\left|s_{21}\right|^2}{(1 - \left|s_{11}\right|^2)(1 - \left|s_{22}\right|^2)} \ dB.$$

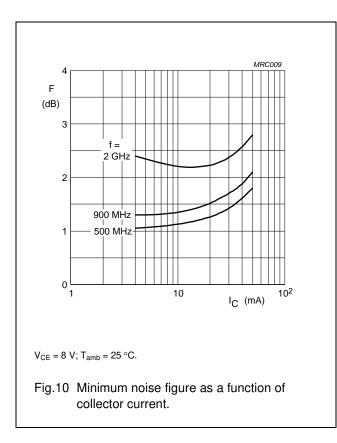
2.  $I_C = 40 \text{ mA}; V_{CE} = 8 \text{ V}; R_L = 50 \Omega; f = 900 \text{ MHz}; T_{amb} = 25 \text{ °C}; f_p = 900 \text{ MHz}; f_q = 902 \text{ MHz}; \text{ measured at } f_{(2p-q)} = 898 \text{ MHz and at } f_{(2q-p)} = 904 \text{ MHz}.$ 

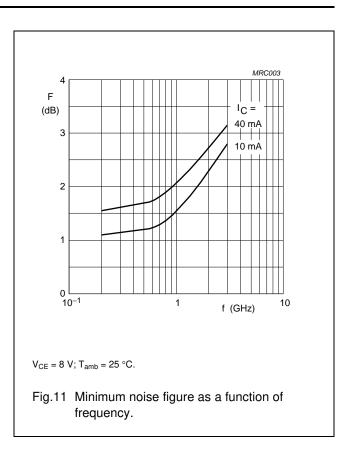


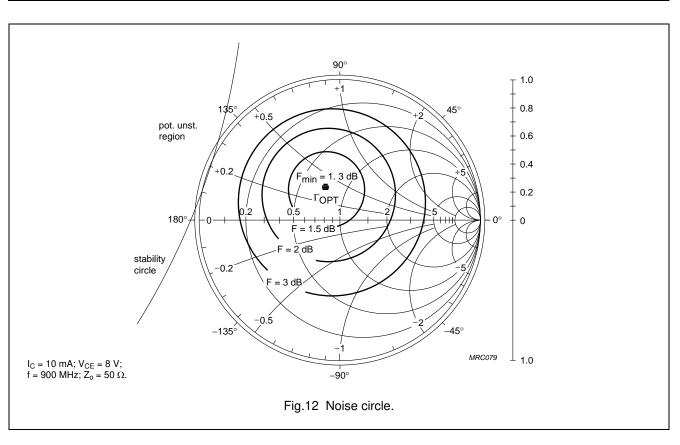
**BFS540** 

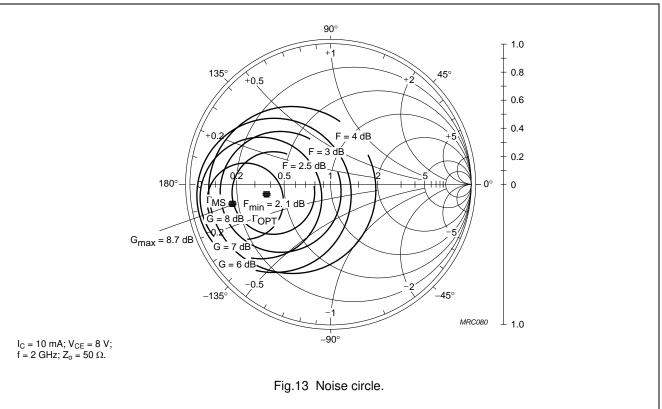
In Figs 6 to 9,  $G_{UM}$  = maximum unilateral power gain; MSG = maximum stable gain;  $G_{max}$  = maximum available gain.

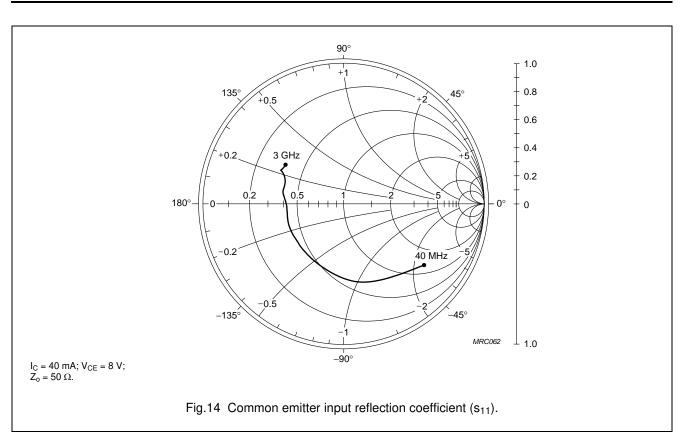


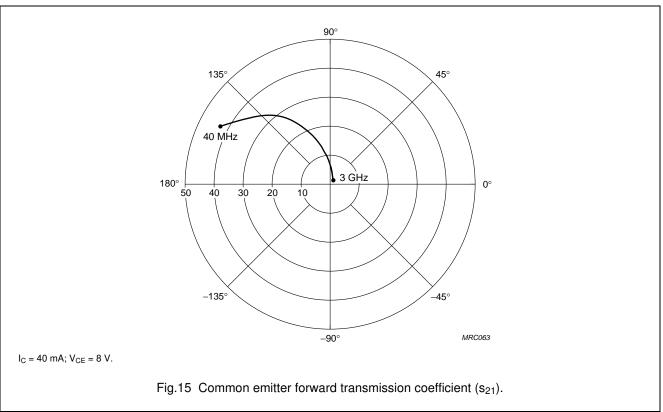


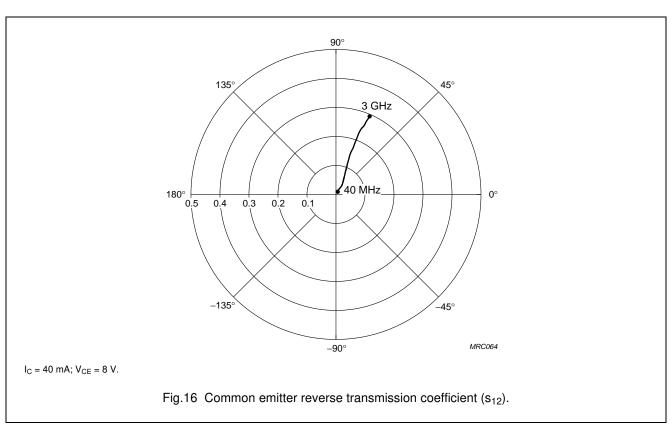


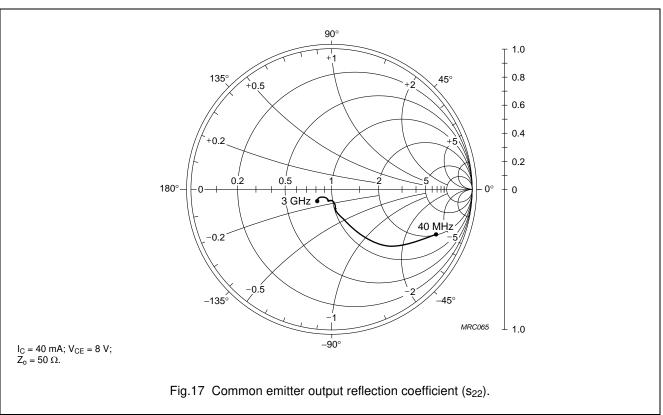




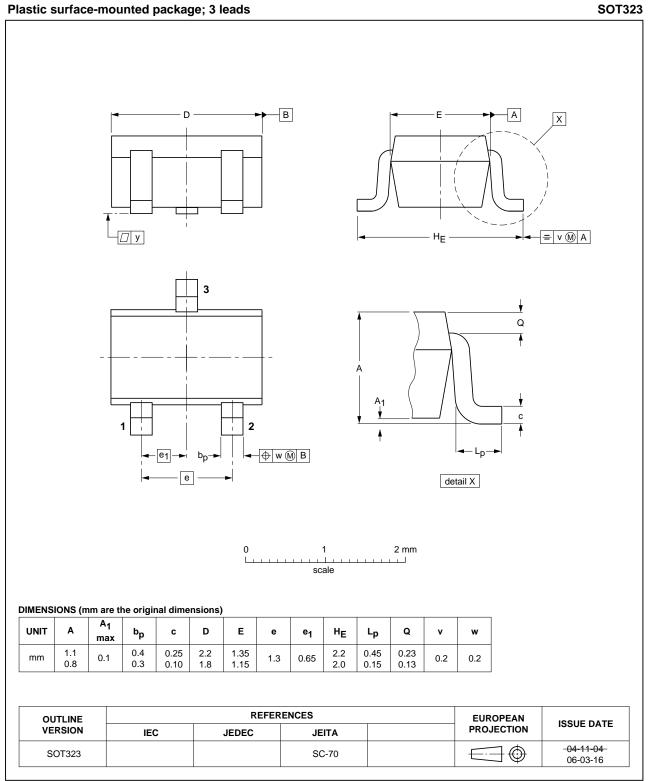








#### PACKAGE OUTLINE



**BFS540** 

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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